

Dual power Schottky diode

Rev.01 - 21 April 2023

Product data sheet

1. General description

Dual common cathode power Schottky diode in TO263 (D2PAK) package.



2. Features and benefits

- High junction temperature up to 175 °C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				150		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 155 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		10		A	
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 153 °C; both diodes conducting			20		A
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 10 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.84	0.93	V
I _R	reverse current	V _R = 150 V; T _i = 25 °C; per diode; <u>Fig. 7</u>		-	0.04	5	μA

Dual power Schottky diode

5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	К	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		6,

6. Ordering information

Table 3. Ordering information									
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
WN3S20150CBT	TO263	WN3S20150CBTJ	Reel	800	TO263d	17-Mar-2023			

7. Marking

Table 4. Marking codes	Table	4.	Marking	codes
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Type number	Marking codes
WN3S20150CBT	WN3S20
	150CBT

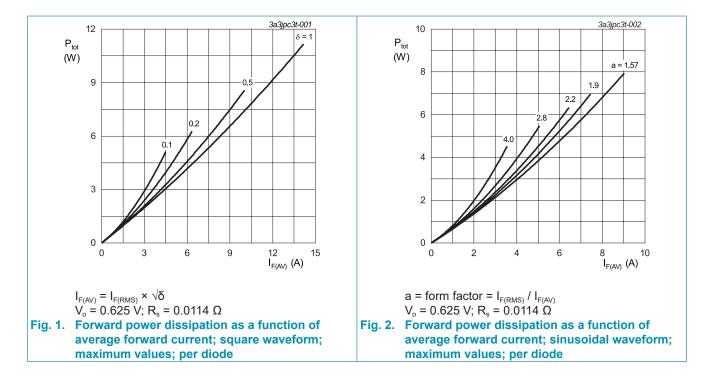
8. Limiting values

Table 5. Limiting values

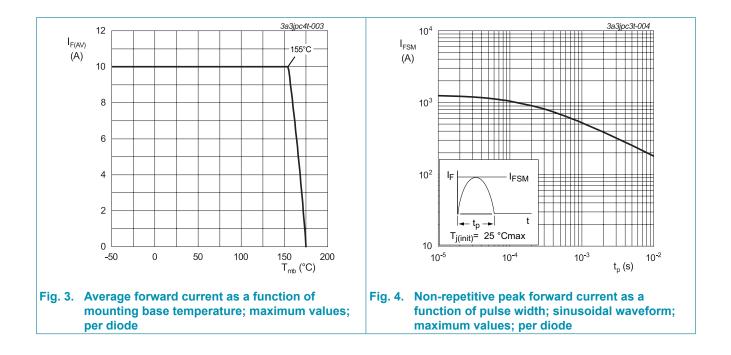
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			150	V
V_{RWM}	crest working reverse voltage			150	V
V _R	reverse voltage	DC		150	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 155 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		10	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 153 °C; both diodes conducting		20	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>		180	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		198	A
T _{stg}	storage temperature			-40 to 175	°C
T _j	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$

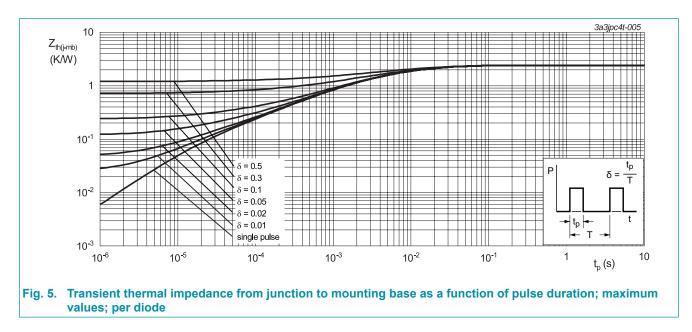


WN3S20150CBT Dual power Schottky diode



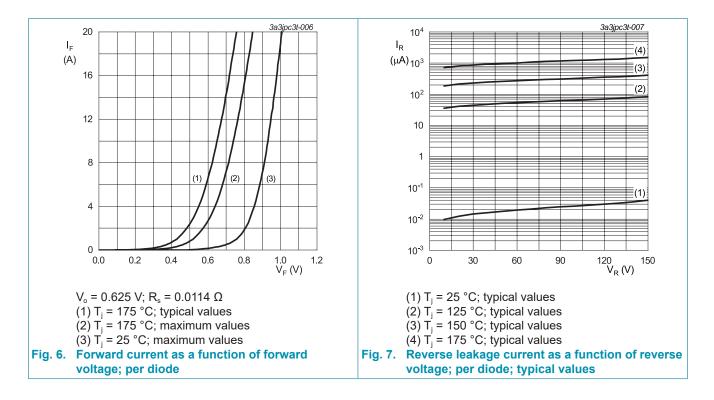
9. Thermal characteristics

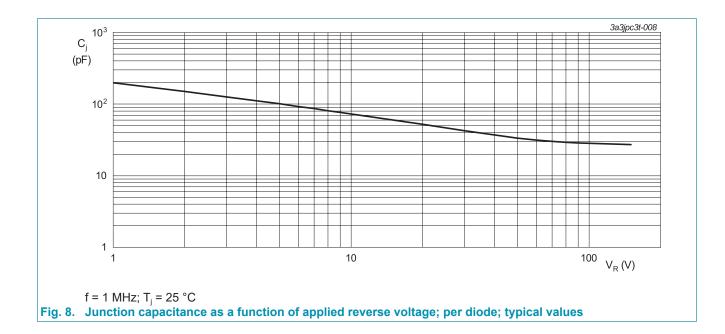
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	th(j-mb) thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>		-	-	2.4	K/W
		both diodes conducting		-	-	1.3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W



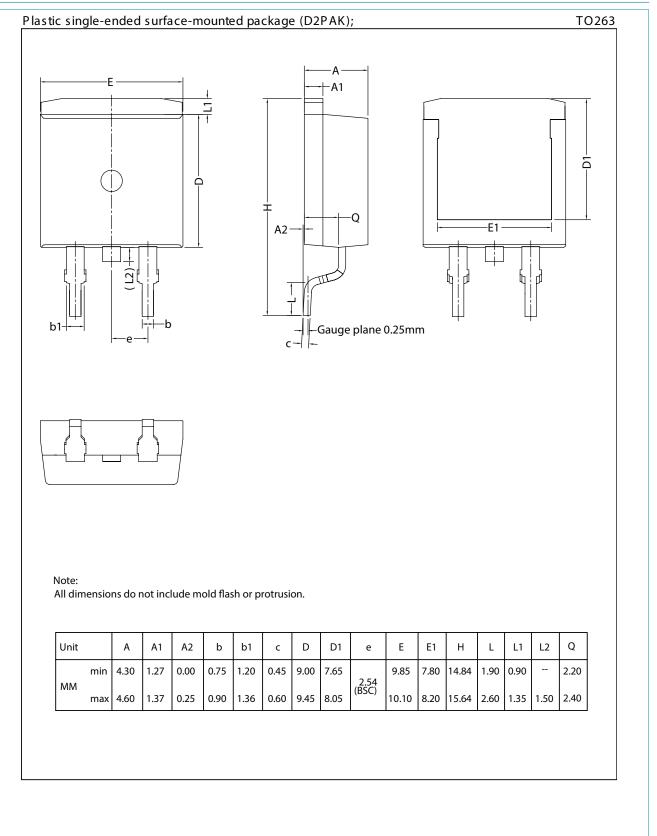
10. Characteristics

Table 7. Cł	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Static characteristics							
$V_{\rm F}$	forward voltage	I _F = 10 A; T _j = 25 °C; per diode; <u>Fig. 6</u>		-	0.84	0.93	V
		I_{F} = 10 A; T_{j} = 125 °C; per diode		-	0.72	-	V
		I _F = 10 A; T _j = 175 °C; per diode; <u>Fig. 6</u>		-	0.65	0.74	V
I _R	reverse current	V_{R} = 150 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.04	5	μA
		V_{R} = 150 V; T _j = 125 °C; per diode; <u>Fig. 7</u>		-	0.09	-	mA





11. Package outline



Dual power Schottky diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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13. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Characteristics	6
11. Package outline	8
12. Legal information	9
13. Contents	

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